Simplify Your Solar Cell Testing with Keithley's Precision Measurement Solutions





Electrical characterization of a variety of solar cell (Photovoltaic) technologies, including:

- Mono Crystalline Si
- Poly Crystalline Si
- Amorphous Si

Measurement of key parameters including:

- Open circuit voltage(Voc)
- Short circuit current (Isc)
- Maximum power output (Pmax) Doping density (N)
- Voltage at Pmax (Vmax)
- Fill factor (ff)
- Series resistance (Rs)

- CIGS
- CdTe
- Polymer Organic

- Shunt resistance (Rsh)
 - Conversion efficiency (η)
 - - · Cell resistivity
 - Defect density

Keithley's solutions for solar cell I-V and C-V characterization provide the most accurate measurements available without the hassles of integrating separate instruments or writing complicated programs.

MODEL 4200-SCS SEMICONDUCTOR CHARACTERIZATION SYSTEM

- Fully integrated I-V and C-V turn key solution with intuitive graphical user interface
- Built-in libraries for extracting key cell parameters, and advanced analytical and formulation tools

SERIES 2400 OR 2600A SOURCEMETER® INSTRUMENTS

- 4-quadrant design provides both source and sink capability for complete I-V
- All-in-one solution for I-V characterization with the combined functionality of a precision power supply, high precision DMM, and electronic load

